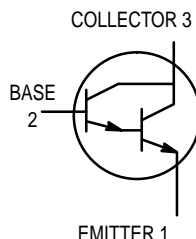
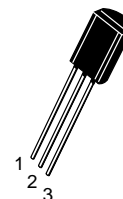


One Watt Darlington Transistors

NPN Silicon



MPS6724
MPS6725



CASE 29-05, STYLE 1
TO-92 (TO-226AE)

MAXIMUM RATINGS

Rating	Symbol	MPS6724	MPS6725	Unit
Collector–Emitter Voltage	V_{CES}	40	50	Vdc
Collector–Base Voltage	V_{CBO}	50	60	Vdc
Emitter–Base Voltage	V_{EBO}	12		Vdc
Collector Current — Continuous	I_C	1000		mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	1.0	8.0	Watts mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	2.5	20	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	50	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage (1) ($I_C = 1.0 \text{ mAdc}, I_E = 0$)	MPS6724 MPS6725	$V_{(BR)CES}$	40 50	— —	Vdc
Collector–Base Breakdown Voltage ($I_C = 1.0 \mu\text{Adc}, I_E = 0$)	MPS6724 MPS6725	$V_{(BR)CBO}$	50 60	— —	Vdc
Emitter–Base Breakdown Voltage ($I_E = 10 \mu\text{Adc}, I_C = 0$)		$V_{(BR)EBO}$	12	—	Vdc
Collector Cutoff Current ($V_{CB} = 30 \text{ Vdc}, I_E = 0$) ($V_{CB} = 40 \text{ Vdc}, I_E = 0$)	MPS6724 MPS6725	I_{CBO}	— —	100 100	nAdc
Emitter Cutoff Current ($V_{EB} = 10 \text{ Vdc}, I_C = 0$)		I_{EBO}	—	100	nAdc

1. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$; Duty Cycle $\leq 2.0\%$.

MPS6724 MPS6725

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS(1)				
DC Current Gain (I _C = 200 mA _{dc} , V _{CE} = 5.0 V _{dc}) (I _C = 1000 mA _{dc} , V _{CE} = 5.0 V _{dc})	h _{FE}	25,000 4,000	— 40,000	—
Collector–Emitter Saturation Voltage (I _C = 1000 mA _{dc} , I _B = 2.0 mA _{dc})	V _{CE(sat)}	—	1.5	V _{dc}
Base–Emitter On Voltage (I _C = 1000 mA _{dc} , V _{CE} = 5.0 V _{dc})	V _{BE(on)}	—	2.0	V _{dc}
SMALL–SIGNAL CHARACTERISTICS				
Current–Gain – Bandwidth Product (I _C = 200 mA _{dc} , V _{CE} = 5.0 V _{dc} , f = 100 MHz)	f _T	100	1000	MHz
Collector–Base Capacitance (V _{CB} = 10 V _{dc} , I _E = 0, f = 1.0 MHz)	C _{cb}	—	10	pF

1. Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2.0%.

TYPICAL CHARACTERISTICS

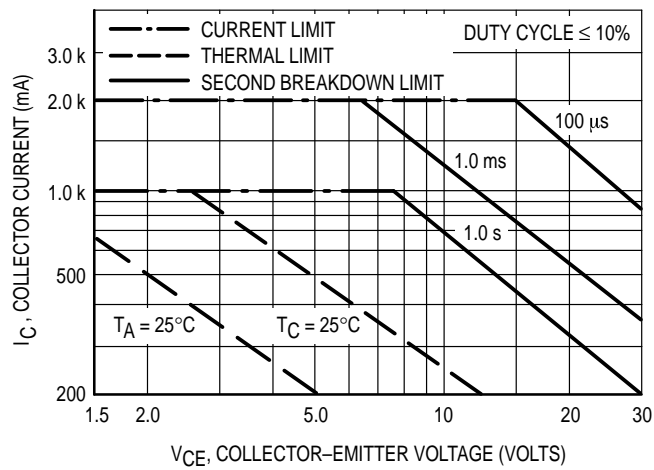


Figure 1. Active Region — Safe Operating Area

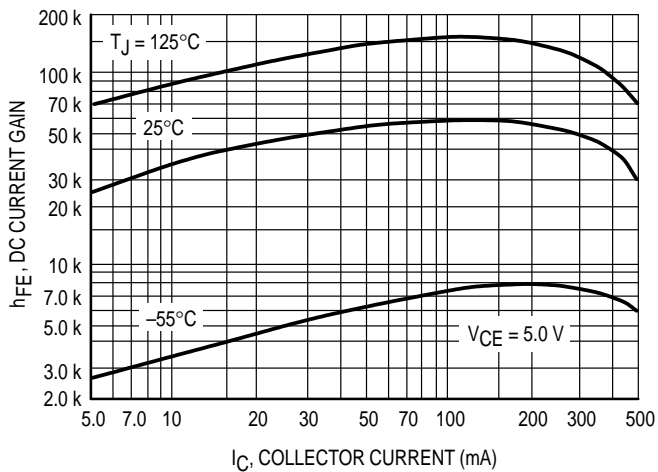


Figure 2. DC Current Gain

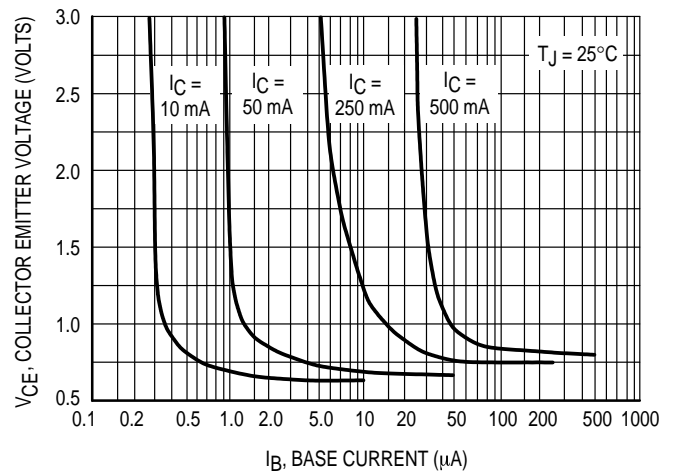


Figure 3. Collector Saturation Region

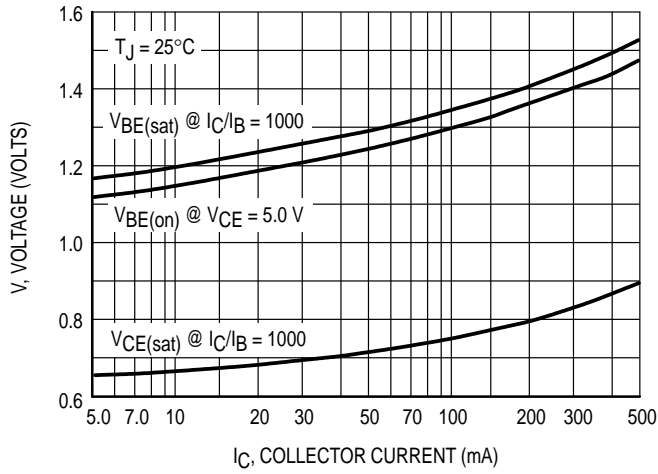


Figure 4. "ON" Voltages

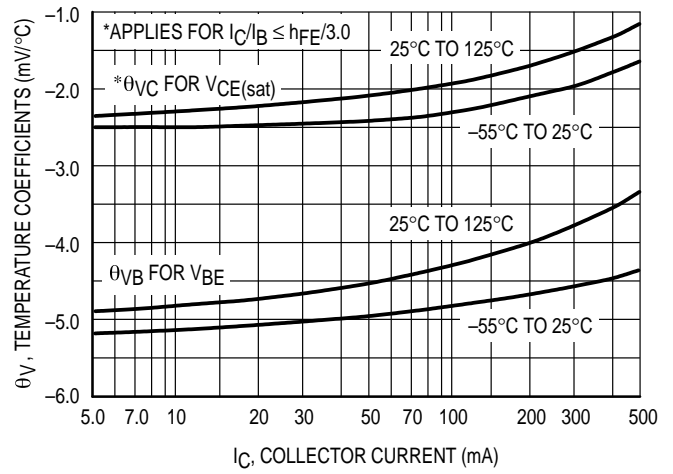


Figure 5. Temperature Coefficients

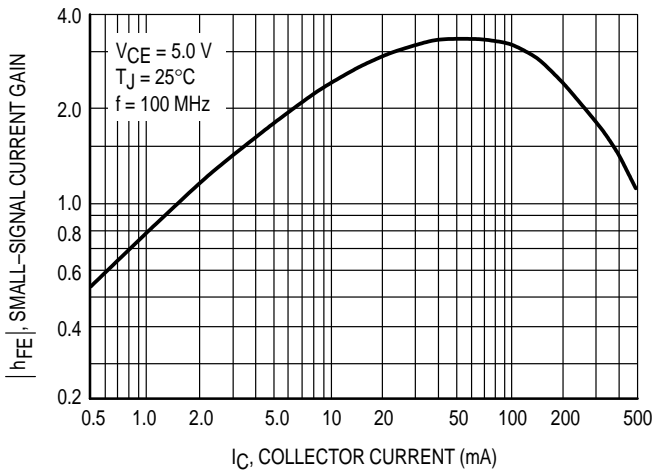


Figure 6. High Frequency Current Gain

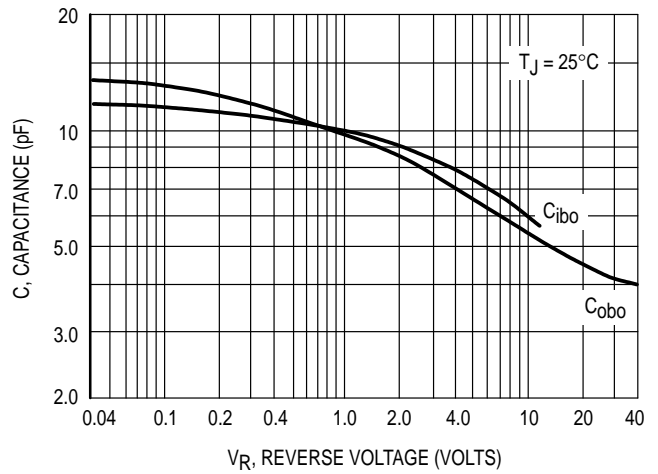
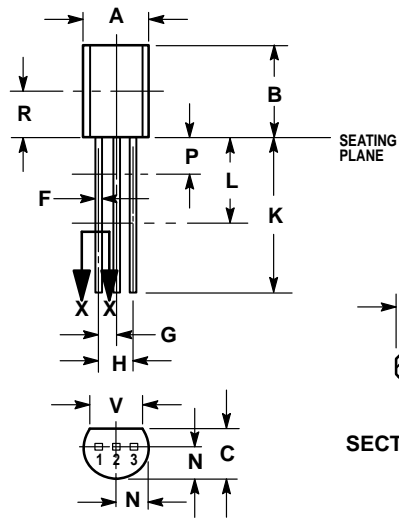


Figure 7. Capacitance

PACKAGE DIMENSIONS



SECTION X-X

CASE 029-05
(TO-226AE)
ISSUE AD


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSIONS D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.44	5.21
B	0.290	0.310	7.37	7.87
C	0.125	0.165	3.18	4.19
D	0.018	0.022	0.46	0.56
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.135	—	3.43	—
V	0.135	—	3.43	—

STYLE 1:

- PIN 1. EMITTER
2. BASE
3. COLLECTOR

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